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November 2004

## Ultra Low Offset Voltage Operational Amplifier

**Features**

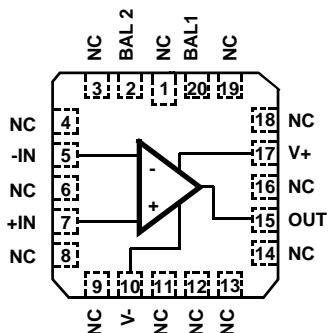
- This Circuit is Processed in Accordance to MIL-STD-883 and is Fully Conformant Under the Provisions of Paragraph 1.2.1.
- Low Offset Voltage .....  **$60\mu\text{V}$  (Max)**  
 **$10\mu\text{V}$  (Typ)**
- Low Offset Voltage Drift .....  **$0.6\mu\text{V}/^\circ\text{C}$  (Max)**  
 **$0.1\mu\text{V}/^\circ\text{C}$  (Typ)**
- High Voltage Gain .....  **$126\text{dB}$  (Min)**  
 **$150\text{dB}$  (Typ)**
- High CMRR .....  **$110\text{dB}$  (Min)**  
 **$140\text{dB}$  (Typ)**
- High PSRR .....  **$110\text{dB}$  (Min)**  
 **$135\text{dB}$  (Typ)**
- Low Noise .....  **$11\text{nV}/\sqrt{\text{Hz}}$  (Max)**  
 **$9\text{nV}/\sqrt{\text{Hz}}$  (Typ)**
- Low Power Consumption .....  **$51\text{mW}$  (Max)**
- Wide Gain Bandwidth Product .....  **$2\text{MHz}$  (Min)**
- Unity Gain Stable

**Applications**

- High Gain Instrumentation Amplifiers
- Precision Control Systems
- Precision Integrators
- High Resolution Data Converters
- Precision Threshold Detectors
- Low Level Transducer Amplifiers

**Pinout**

HA-5177/883  
(CLCC)  
TOP VIEW



**Absolute Maximum Ratings**

|  |                               |
|--|-------------------------------|
| Voltage Between V+ and V- Terminals . . . . .    | 44V                           |
| Differential Input Voltage (Note 1) . . . . .    | 7V                            |
| Voltage at Either Input Terminal . . . . .       | V+ to V-                      |
| Input Current . . . . .                          | 25mA                          |
| Output Current . . . . .                         | Full Short Circuit Protection |
| Junction Temperature (T <sub>J</sub> ) . . . . . | +175°C                        |
| Storage Temperature Range . . . . .              | -65°C to +150°C               |
| ESD Rating . . . . .                             | <2000V                        |
| Lead Temperature (Soldering 10s) . . . . .       | +300°C                        |

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

**NOTE:**

1. θ<sub>JA</sub> is measured with the component mounted on a low effective thermal conductivity test board in free air. See Tech Brief TB379 for details.

**Operating Conditions**

|                                       |                 |                                   |
|---------------------------------------|-----------------|-----------------------------------|
| Operating Temperature Range . . . . . | -55°C to +125°C | V <sub>INCM</sub> ≤ 1/2 (V+ - V-) |
| Operating Supply Voltage . . . . .    | ±15V            | R <sub>L</sub> ≥ 600Ω             |

**TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS**

Device Tested at: V<sub>SUPPLY</sub> = ±15V, R<sub>SOURCE</sub> = 50Ω, R<sub>LOAD</sub> = 100kΩ, V<sub>OUT</sub> = 0V, Unless Otherwise Specified.

| PARAMETERS                  | SYMBOL             | CONDITIONS   | GROUP A<br>SUBGROUPS | TEMPERATURE   | LIMITS |     | UNITS |
|-----------------------------|--------------------|--|----------------------|---------------|--------|-----|-------|
|                             |                    |  |                      |               | MIN    | MAX |       |
| Input Offset Voltage        | V <sub>IO</sub>    | V <sub>CM</sub> = 0V   | 1                    | +25°C         | -60    | 60  | µV    |
|                             |                    |  | 2, 3                 | +125°C, -55°C | -100   | 100 | µV    |
| Input Bias Current          | I <sub>B</sub>     | V <sub>CM</sub> = 0V,<br>R <sub>S</sub> = 10kΩ, 50Ω<br>$\left(\frac{ I_B  +  -I_B }{2}\right)$ | 1                    | +25°C         | -6     | 6   | nA    |
|                             |                    |  | 2, 3                 | +125°C, -55°C | -8     | 8   | nA    |
| Input Offset Current        | I <sub>IO</sub>    | V <sub>CM</sub> = 0V,<br>+R <sub>S</sub> = 10kΩ,<br>-R <sub>S</sub> = 10kΩ                     | 1                    | +25°C         | -6     | 6   | nA    |
|                             |                    |  | 2, 3                 | +125°C, -55°C | -8     | 8   | nA    |
| Common Mode Range           | +CMR               | V+ = +3V, V- = -27V  | 1                    | +25°C         | 12     | -   | V     |
|                             |                    |  | 2, 3                 | +125°C, -55°C | 12     | -   | V     |
|                             | -CMR               | V+ = +27V, V- = -3V  | 1                    | +25°C         | -      | -12 | V     |
|                             |                    |  | 2, 3                 | +125°C, -55°C | -      | -12 | V     |
| Large Signal Voltage Gain   | +A <sub>VOL</sub>  | V <sub>OUT</sub> = 0V and +10V,<br>R <sub>L</sub> = 2kΩ  | 4                    | +25°C         | 126    | -   | dB    |
|                             |                    |  | 5, 6                 | +125°C, -55°C | 120    | -   | dB    |
|                             | -A <sub>VOL</sub>  | V <sub>OUT</sub> = 0V and -10V,<br>R <sub>L</sub> = 2kΩ  | 4                    | +25°C         | 126    | -   | dB    |
|                             |                    |  | 5, 6                 | +125°C, -55°C | 120    | -   | dB    |
| Common Mode Rejection Ratio | +CMRR              | ΔV <sub>CM</sub> = 10V,<br>V+ = +5V, V- = -25V,<br>V <sub>OUT</sub> = -10                      | 1                    | +25°C         | 116    | -   | dB    |
|                             |                    |  | 2, 3                 | +125°C, -55°C | 110    | -   | dB    |
|                             | -CMRR              | ΔV <sub>CM</sub> = 10V,<br>V+ = +25V, V- = -5V,<br>V <sub>OUT</sub> = +10                      | 1                    | +25°C         | 116    | -   | dB    |
|                             |                    |  | 2, 3                 | +125°C, -55°C | 110    | -   | dB    |
| Output Voltage Swing        | +V <sub>OUT1</sub> | R <sub>L</sub> = 2kΩ   | 4                    | +25°C         | 12     | -   | V     |
|                             |                    |  | 5, 6                 | +125°C, -55°C | 12     | -   | V     |
|                             | -V <sub>OUT1</sub> | R <sub>L</sub> = 2kΩ   | 4                    | +25°C         | -      | -12 | V     |
|                             |                    |  | 5, 6                 | +125°C, -55°C | -      | -12 | V     |
|                             | +V <sub>OUT2</sub> | R <sub>L</sub> = 600Ω  | 4                    | +25°C         | 10     | -   | V     |
|                             | -V <sub>OUT2</sub> | R <sub>L</sub> = 600Ω  | 4                    | +25°C         | -      | -10 | V     |

**Thermal Information**

|  |                 |                 |
|--|-----------------|-----------------|
| Thermal Resistance   | θ <sub>JA</sub> | θ <sub>JC</sub> |
| Ceramic LCC Package  | 80°C/W          | 28°C/W          |
| Package Power Dissipation Limit at +75°C for T <sub>J</sub> ≤ +175°C |                 |                 |
| Ceramic LCC Package  |                 | 1.54W           |
| Package Power Dissipation Derating Factor Above +75°C                |                 |                 |
| Ceramic LCC Package  |                 | 15.4mW/°C       |

TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS (Continued)

Device Tested at:  $V_{SUPPLY} = \pm 15V$ ,  $R_{SOURCE} = 50\Omega$ ,  $R_{LOAD} = 100k\Omega$ ,  $V_{OUT} = 0V$ , Unless Otherwise Specified.

| PARAMETERS                     | SYMBOL       | CONDITIONS  | GROUP A<br>SUBGROUPS | TEMPERATURE                   | LIMITS |      | UNITS |
|--------------------------------|--------------|---|----------------------|-------------------------------|--------|------|-------|
|                                |              |   |                      |                               | MIN    | MAX  |       |
| Output Current                 | $+I_{OUT}$   | $V_{OUT} = -10V$  | 4                    | $+25^{\circ}C$                | 15     | -    | mA    |
|                                |              |   | 5, 6                 | $+125^{\circ}C, -55^{\circ}C$ | 15     | -    | mA    |
|                                | $-I_{OUT}$   | $V_{OUT} = +10V$  | 4                    | $+25^{\circ}C$                | -      | -15  | mA    |
|                                |              |   | 5, 6                 | $+125^{\circ}C, -55^{\circ}C$ | -      | -15  | mA    |
| Quiescent Power Supply Current | $+I_{CC}$    | $V_{OUT} = 0V, I_{OUT} = 0mA$   | 1                    | $+25^{\circ}C$                | -      | 1.7  | mA    |
|                                |              |   | 2, 3                 | $+125^{\circ}C, -55^{\circ}C$ | -      | 1.7  | mA    |
|                                | $-I_{CC}$    | $V_{OUT} = 0V, I_{OUT} = 0mA$   | 1                    | $+25^{\circ}C$                | -1.7   | -    | mA    |
|                                |              |   | 2, 3                 | $+125^{\circ}C, -55^{\circ}C$ | -1.7   | -    | mA    |
| Power Supply Rejection Ratio   | $+PSRR$      | $\Delta V_{SUP} = 15V, V_+ = +5V, V_- = -15V, V_+ = +20V, V_- = -15V$ | 1                    | $+25^{\circ}C$                | 110    | -    | dB    |
|                                |              |   | 2, 3                 | $+125^{\circ}C, -55^{\circ}C$ | 110    | -    | dB    |
|                                | $-PSRR$      | $\Delta V_{SUP} = 15V, V_+ = +15V, V_- = -5V, V_+ = +15V, V_- = -20V$ | 1                    | $+25^{\circ}C$                | 110    | -    | dB    |
|                                |              |   | 2, 3                 | $+125^{\circ}C, -55^{\circ}C$ | 110    | -    | dB    |
| Offset Voltage Adjustment      | $+V_{IOAdj}$ | Note 2  | 1                    | $+25^{\circ}C$                | 0.3    | -    | mV    |
|                                |              |   | 2, 3                 | $+125^{\circ}C, -55^{\circ}C$ | 0.3    | -    | mV    |
|                                | $-V_{IOAdj}$ | Note 2  | 1                    | $+25^{\circ}C$                | -      | -0.3 | mV    |
|                                |              |   | 2, 3                 | $+125^{\circ}C, -55^{\circ}C$ | -      | -0.3 | mV    |

## NOTES:

1. The input stage has series  $500\Omega$  resistors along with back to back diodes. This provides large differential input voltage protection for a slight increase in noise voltage.
2. This test is for functionality only to assure adjustment through 0V.

TABLE 2. AC ELECTRICAL PERFORMANCE CHARACTERISTICS

Device Tested at:  $V_{SUPPLY} = \pm 15V$ ,  $R_{SOURCE} = 50\Omega$ ,  $R_{LOAD} = 2k\Omega$ ,  $C_{LOAD} = 50pF$ ,  $A_{VCL} = +1V/V$ , Unless Otherwise Specified.

| PARAMETERS         | SYMBOL | CONDITIONS  | GROUP A<br>SUBGROUPS | TEMPERATURE    | LIMITS |     | UNITS     |
|--------------------|--------|---|----------------------|----------------|--------|-----|-----------|
|                    |        |   |                      |                | MIN    | MAX |           |
| Slew Rate          | $+SR$  | $V_{OUT} = -3V$ to $+3V$ , $V_{IN}$ S.R. $\leq 25V/\mu s$ | 7                    | $+25^{\circ}C$ | 0.5    | -   | $V/\mu s$ |
|                    | $-SR$  | $V_{OUT} = +3V$ to $-3V$ , $V_{IN}$ S.R. $\leq 25V/\mu s$ | 7                    | $+25^{\circ}C$ | 0.5    | -   | $V/\mu s$ |
| Rise and Fall Time | $t_R$  | $V_{OUT} = 0$ to $+200mV$ $10\% \leq T_R \leq 90\%$       | 7                    | $+25^{\circ}C$ | -      | 420 | ns        |
|                    | $t_F$  | $V_{OUT} = 0$ to $-200mV$ $10\% \leq T_F \leq 90\%$       | 7                    | $+25^{\circ}C$ | -      | 420 | ns        |
| Overshoot          | $+OS$  | $V_{OUT} = 0$ to $+200mV$                                 | 7                    | $+25^{\circ}C$ | -      | 40  | %         |
|                    | $-OS$  | $V_{OUT} = 0$ to $-200mV$                                 | 7                    | $+25^{\circ}C$ | -      | 40  | %         |

TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS

Device Characterized at:  $V_{SUPPLY} = \pm 15V$ ,  $R_{LOAD} = 2k\Omega$ ,  $C_{LOAD} = 50pF$ ,  $A_V = +1V/V$ , Unless Otherwise Specified.

| PARAMETERS                               | SYMBOL     | CONDITIONS                                    | NOTES | TEMPERATURE     | LIMITS |     | UNITS                 |
|--|------------|---|-------|-----------------|--------|-----|-----------------------|
|  |            |   |       |                 | MIN    | MAX |                       |
| Average Offset Voltage Drift             | $V_{IO}TC$ | $V_{CM} = 0V$                                 | 1     | -55°C to +125°C | -      | 0.6 | $\mu V/\text{°C}$     |
| Average Offset Current Drift             | $I_{IO}TC$ | Versus Temperature                            | 1     | -55°C to +125°C | -      | 40  | $pA/\text{°C}$        |
| Average Bias Current Drift               | $I_{RTC}$  | Versus Temperature                            | 1     | -55°C to +125°C | -      | 40  | $pA/\text{°C}$        |
| Differential Input Resistance            | $R_{IN}$   | $V_{CM} = 0V$                                 | 1     | +25°C           | 20     | -   | $M\Omega$             |
| Low Frequency Peak-to-Peak Noise Voltage | $E_{NP-P}$ | 0.1Hz to 10Hz                                 | 1     | +25°C           | -      | 0.6 | $\mu V_{P-P}$         |
| Low Frequency Peak-to-Peak Noise Current | $I_{NP-P}$ | 0.1Hz to 10Hz                                 | 1     | +25°C           | -      | 45  | $pA_{P-P}$            |
| Input Noise Voltage Density              | $E_N$      | $R_S = 20\Omega$ , $f_O = 10Hz$               | 1     | +25°C           | -      | 18  | $nV/\sqrt{\text{Hz}}$ |
|  |            | $R_S = 20\Omega$ , $f_O = 100Hz$              | 1     | +25°C           | -      | 13  | $nV/\sqrt{\text{Hz}}$ |
|  |            | $R_S = 20\Omega$ , $f_O = 1kHz$               | 1     | +25°C           | -      | 11  | $nV/\sqrt{\text{Hz}}$ |
| Input Noise Current Density              | $I_N$      | $R_S = 2M\Omega$ , $f_O = 10Hz$               | 1     | +25°C           | -      | 4   | $pA/\sqrt{\text{Hz}}$ |
|  |            | $R_S = 2M\Omega$ , $f_O = 100Hz$              | 1     | +25°C           | -      | 2.3 | $pA/\sqrt{\text{Hz}}$ |
|  |            | $R_S = 2M\Omega$ , $f_O = 1kHz$               | 1     | +25°C           | -      | 1   | $pA/\sqrt{\text{Hz}}$ |
| Gain Bandwidth Product                   | GBWP       | $V_O = 100mV$ ,<br>$1Hz \leq f_O \leq 100kHz$ | 1     | +25°C           | 2      | -   | MHz                   |
| Full Power Bandwidth                     | FPBW       | $V_{PEAK} = 10V$                              | 1, 2  | +25°C           | 8      | -   | kHz                   |
| Minimum Closed Loop Stable Gain          | CLSG       | $R_L = 2k\Omega$ , $C_L = 50pF$               | 1     | -55°C to +125°C | +1     | -   | $V/V$                 |
| Settling Time                            | $t_S$      | To 0.1% for a 10V Step                        | 1     | +25°C           | -      | 15  | $\mu s$               |
| Output Resistance                        | $R_{OUT}$  | Open Loop                                     | 1     | +25°C           | -      | 70  | $\Omega$              |
| Power Consumption                        | PC         | $V_{OUT} = 0V$ , $I_{OUT} = 0mA$              | 1, 3  | -55°C to +125°C | -      | 51  | mW                    |

## NOTES:

- Parameters listed in Table 3 are controlled via design or process parameters and are not directly tested at final production. These parameters are lab characterized upon initial design release, or upon design changes. These parameters are guaranteed by characterization based upon data from multiple production runs which reflect lot to lot and within lot variation.
- Full Power Bandwidth guarantee based on Slew Rate measurement using  $FPBW = \text{Slew Rate}/(2\pi V_{PEAK})$ .
- Power Consumption based upon Quiescent Supply Current test maximum. (No load on outputs.)

TABLE 4. ELECTRICAL TEST REQUIREMENTS

| MIL-STD-883 TEST REQUIREMENTS               | SUBGROUPS (SEE TABLES 1 AND 2) |
|---|--------------------------------|
| Interim Electrical Parameters (Pre Burn-In) | 1                              |
| Final Electrical Test Parameters            | 1 (Note 1), 2, 3, 4, 5, 6, 7   |
| Group A Test Requirements                   | 1, 2, 3, 4, 5, 6, 7            |
| Groups C and D Endpoints                    | 1                              |

## NOTE:

- PDA applies to Subgroup 1 only.

## Die Characteristics

### DIE DIMENSIONS:

72 x 103 x 19 mils  $\pm$  1 mils  
 1840 x 2620 x 483 $\mu$ m  $\pm$  25.4 $\mu$ m

### METALLIZATION:

Type: Al, 1% Cu  
 Thickness: 16k $\text{\AA}$   $\pm$  2k $\text{\AA}$

### GLASSIVATION:

Type: Nitride (Si<sub>3</sub>N<sub>4</sub>) over Silox (SiO<sub>2</sub>, 5% Phos.)  
 Silox Thickness: 12k $\text{\AA}$   $\pm$  2k $\text{\AA}$   
 Nitride Thickness: 3.5k $\text{\AA}$   $\pm$  1.5k $\text{\AA}$

### WORST CASE CURRENT DENSITY:

6.0 x 10<sup>4</sup>A/cm<sup>2</sup>

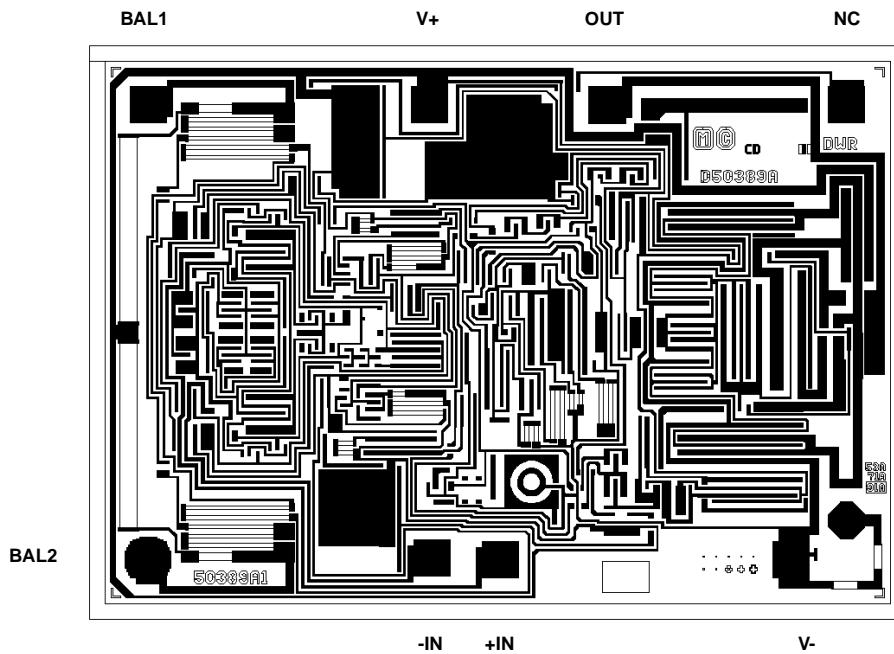
### SUBSTRATE POTENTIAL (Powered Up): V-

### TRANSISTOR COUNT: 71

### PROCESS: Bipolar Dielectric Isolation

## Metallization Mask Layout

HA-5177/883



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